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NTE328 Silicon NPN Transistor Power Amp, Switch

Description:

The NTE328 is a silicon NPN transistor in a TO3 type package designed for use in industrial power amplifier and switching circuit applications.

Features:

- High Collector-Emitter Sustaining Voltage
- High DC Current Gain
- Low Collector-Emitter Saturation Voltage
- Fast Switching Times

Absolute Maximum Ratings:

Collector-Emitter Voltage, V_{CEO}	120V
Collector-Base Voltage, V_{CB}	140V
Emitter-Base Voltage, V_{EB}	6V
Collector Current, I_C	
Continuous	25A
Peak	50A
Base Current, I_B	10A
Total Device Dissipation ($T_C = +25^\circ\text{C}$), P_D	200W
Derate Above 25°C	1.14W/ $^\circ\text{C}$
Operating Junction Temperature Range, T_J	-65° to +200° $^\circ\text{C}$
Storage Temperature Range, T_{stg}	-65° to +200° $^\circ\text{C}$
Thermal Resistance, Junction-to-Case, R_{thJC}	0.875° $^\circ\text{C}/\text{W}$

Electrical Characteristics: ($T_C = +25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
OFF Characteristics						
Collector-Emitter Sustaining Voltage	$V_{CEO(sus)}$	$I_C = 50\text{mA}$, $I_B = 0$, Note 1	120	—	—	V
Collector Cutoff Current	I_{CEX}	$V_{CE} = 120\text{V}$, $V_{BE(off)} = 1.5\text{V}$	—	—	10	mA
		$V_{CE} = 120\text{V}$, $V_{BE(off)} = 1.5\text{V}$, $T_C = +150^\circ\text{C}$	—	—	1.0	mA
	I_{CEO}	$V_{CE} = 60\text{V}$, $I_B = 0$	—	—	50	μA
	I_{CBO}	$V_{CB} = 180\text{V}$, $I_E = 0$	—	—	10	μA
Emitter Cutoff Current	I_{EBO}	$V_{BE} = 6\text{V}$, $I_C = 0$	—	—	100	μA

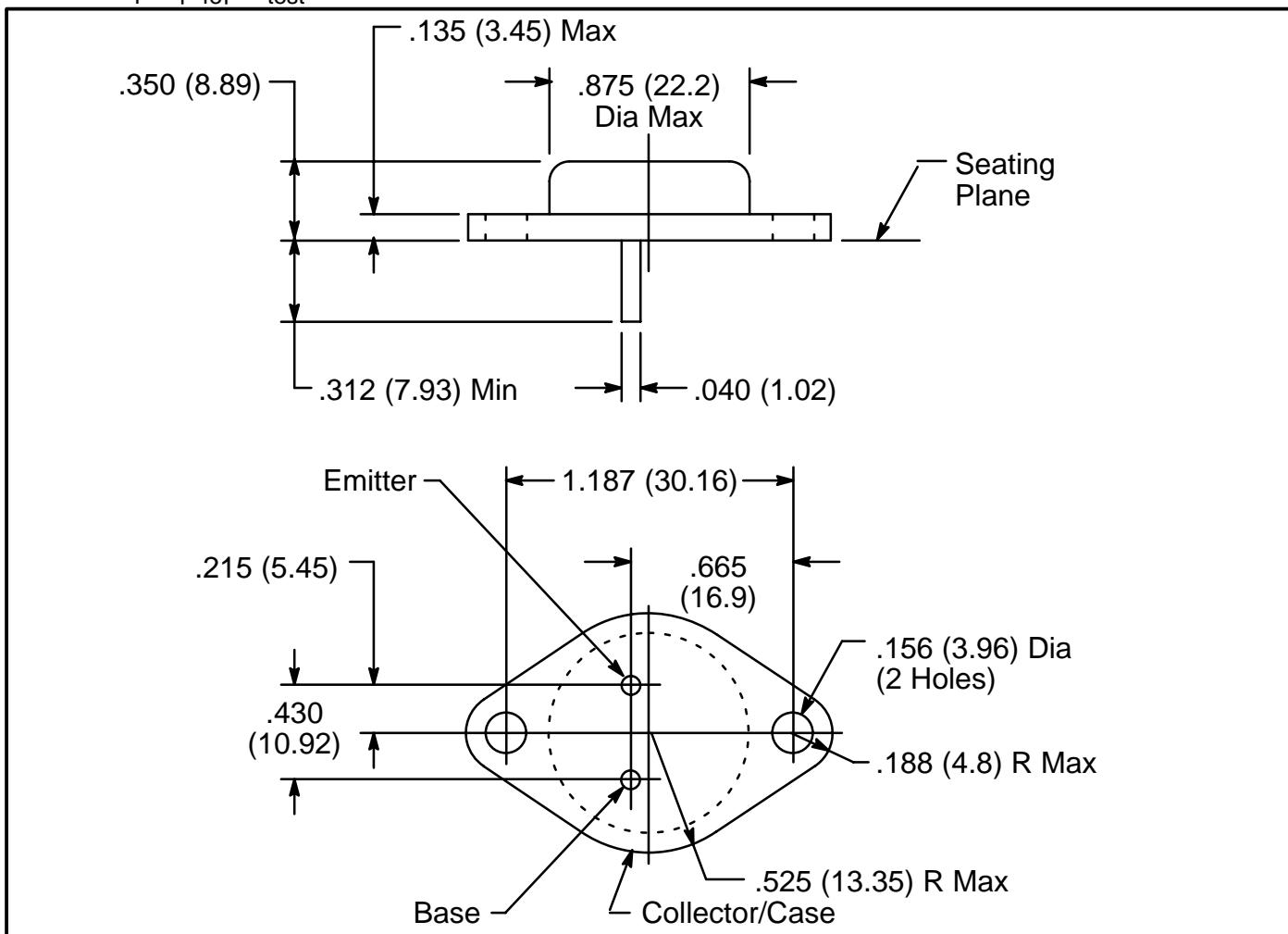
Note 1. Pulse test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$.

Electrical Characteristics (Cont'd): ($T_C = +25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
ON Characteristics (Note 1)						
DC Current Gain	h_{FE}	$V_{CE} = 2\text{V}, I_C = 0.5\text{A}$	50	—	—	
		$V_{CE} = 2\text{V}, I_C = 10\text{A}$	30	—	120	
		$V_{CE} = 2\text{V}, I_C = 25\text{A}$	12	—	—	
Collector-Emitter Saturation Voltage	$V_{CE(\text{sat})}$	$I_C = 10\text{A}, I_B = 1.0\text{A}$	—	—	1.0	V
		$I_C = 25\text{A}, I_B = 2.5\text{A}$	—	—	1.8	V
Base-Emitter Saturation Voltage	$V_{BE(\text{sat})}$	$I_C = 10\text{A}, I_B = 1.0\text{A}$	—	—	1.8	V
		$I_C = 25\text{A}, I_B = 2.5\text{A}$	—	—	2.5	V
Base-Emitter ON Voltage	$V_{BE(\text{on})}$	$V_{CE} = 2\text{V}, I_C = 10\text{A}$	—	—	1.8	V
Dymanic Characteristics						
Current Gain-Bandwidth Product	f_T	$V_{CE} = 10\text{V}, I_C = 1\text{A}, f = 10\text{MHz}$, Note 2	40	—	—	MHz
Output Capacitance	C_{ob}	$V_{CB} = 10\text{V}, I_E = 0, f = 0.1\text{MHz}$	—	—	300	pF
Switching Characteristics						
Rise Time	t_r	$V_{CC} = 80\text{V}, I_C = 10\text{A}, I_{B1} = 1\text{A}, V_{BE(\text{off})} = 6\text{v}$	—	—	0.3	μs
Storage Time	t_s	$V_{CC} = 80\text{V}, I_C = 10\text{A}, I_{B1} = I_{B2} = 1\text{A}$	—	—	1.0	μs
Fall Time	t_f		—	—	0.25	μs

Note 1. Pulse test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$.

Note 2. $f_T = |h_{fe}| \cdot f_{\text{test}}$.



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